

CD4023BM/CD4023BC
Buffered Triple 3-Input NAND Gate
CD4025BM/CD4025BC
Buffered Triple 3-Input NOR Gate

General Description

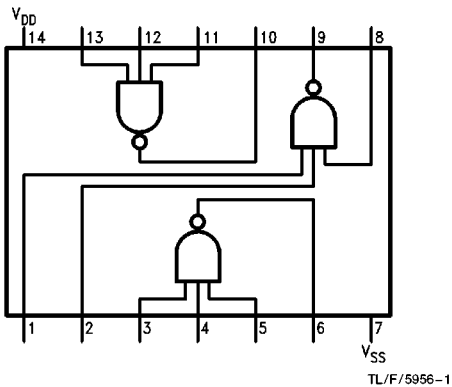
These triple gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N- and P-channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain. All inputs are protected against static discharge with diodes to V_{DD} and V_{SS} .

Features

- Wide supply voltage range 3.0V to 15V
- High noise immunity 0.45 V_{DD} (typ.)
- Low power TTL compatibility fan out of 2 driving 74L or 1 driving 74LS
- 5V–10V–15V parametric ratings
- Symmetrical output characteristics
- Maximum input leakage 1 μ A at 15V over full temperature range

Connection Diagrams

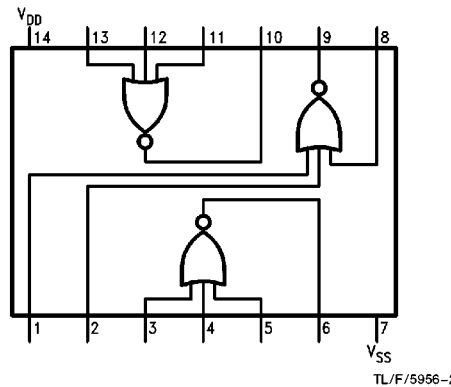
CD4023BM/CD4023BC
Dual-In-Line Package



Top View

TL/F/5956-1

CD4025BM/CD4025BC
Dual-In-Line Package



Top View

TL/F/5956-2

Order Number CD4023B or CD4025B

CD4023BM/CD4023BC Buffered Triple 3-Input NAND Gate
CD4025BM/CD4025BC Buffered Triple 3-Input NOR Gate

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

| | |
|--------------------------------|--|
| DC Supply Voltage (V_{DD}) | -0.5 V_{DC} to +18 V_{DC} |
| Input Voltage (V_{IN}) | -0.5 V_{DC} to V_{DD} + 0.5 V_{DC} |
| Storage Temp. Range (T_S) | -65°C to +150°C |
| Power Dissipation (P_D) | |
| Dual-In-Line | 700 mW |
| Small Outline | 500 mW |
| Lead Temperature (T_L) | |
| (Soldering, 10 seconds) | 260°C |

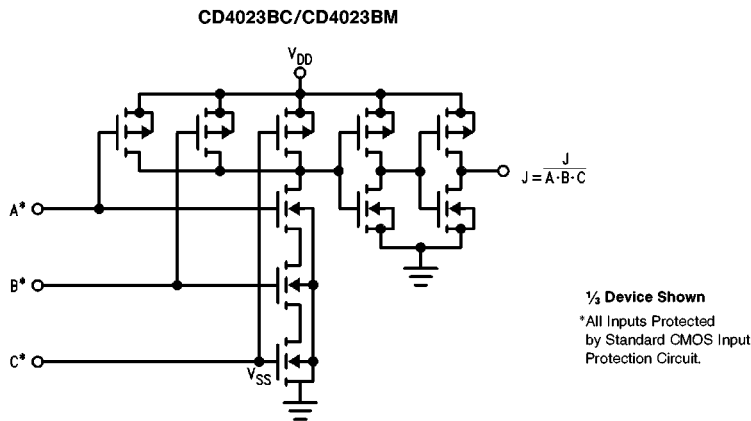
Recommended Operating Conditions

| | |
|---------------------------------------|---------------------------------|
| DC Supply Voltage (V_{DD}) | 5 V_{DC} to 15 V_{DC} |
| Input Voltage (V_{IN}) | 0 V_{DC} to V_{DD} V_{DC} |
| Operating Temperature Range (T_A) | |
| CD4023BM, CD4025BM | -55°C to +125°C |
| CD4023BC, CD4025BC | -40°C to +85°C |

DC Electrical Characteristics CD4023BM, CD4025BM (Note 2)

| Symbol | Parameter | Conditions | -55°C | | +25°C | | | +125°C | | Units |
|----------|------------------------------------|------------------------------|-------|-------|-------|-------------------|-------|--------|------|---------|
| | | | Min | Typ | Min | Typ | Max | Min | Max | |
| I_{DD} | Quiescent Device Current | $V_{DD} = 5V$ | | 0.25 | | 0.004 | 0.25 | | 7.5 | μA |
| | | $V_{DD} = 10V$ | | 0.5 | | 0.005 | 0.5 | | 15 | μA |
| | | $V_{DD} = 15V$ | | 1.0 | | 0.006 | 1.0 | | 30 | μA |
| V_{OL} | Low Level Output Voltage | $V_{DD} = 5V$ | | 0.05 | | 0 | 0.05 | | 0.05 | V |
| | | $V_{DD} = 10V$ | | 0.05 | | 0 | 0.05 | | 0.05 | V |
| | | $V_{DD} = 15V$ | | 0.05 | | 0 | 0.05 | | 0.05 | V |
| V_{OH} | High Level Output Voltage | $V_{DD} = 5V$ | 4.95 | | 4.95 | 5 | | 4.95 | | V |
| | | $V_{DD} = 10V$ | 9.95 | | 9.95 | 10 | | 9.95 | | V |
| | | $V_{DD} = 15V$ | 14.95 | | 14.95 | 15 | | 14.95 | | V |
| V_{IL} | Low Level Input Voltage | $V_{DD} = 5V, V_O = 4.5V$ | | 1.5 | | 2 | 1.5 | | 1.5 | V |
| | | $V_{DD} = 10V, V_O = 9.0V$ | | 3.0 | | 4 | 3.0 | | 3.0 | V |
| | | $V_{DD} = 15V, V_O = 13.5V$ | | 4.0 | | 6 | 4.0 | | 4.0 | V |
| V_{IH} | High Level Input Voltage | $V_{DD} = 5V, V_O = 0.5V$ | 3.5 | | 3.5 | 3 | | 3.5 | | V |
| | | $V_{DD} = 10V, V_O = 1.0V$ | 7.0 | | 7.0 | 6 | | 7.0 | | V |
| | | $V_{DD} = 15V, V_O = 1.5V$ | 11.0 | | 11.0 | 9 | | 11.0 | | V |
| I_{OL} | Low Level Output Current (Note 3) | $V_{DD} = 5V, V_O = 0.4V$ | 0.64 | | 0.51 | 0.88 | | 0.36 | | mA |
| | | $V_{DD} = 10V, V_O = 0.5V$ | 1.6 | | 1.3 | 2.2 | | 0.90 | | mA |
| | | $V_{DD} = 15V, V_O = 1.5V$ | 4.2 | | 3.4 | 8 | | 2.4 | | mA |
| I_{OH} | High Level Output Current (Note 3) | $V_{DD} = 5V, V_O = 4.6V$ | -0.64 | | -0.51 | -0.88 | | -0.36 | | mA |
| | | $V_{DD} = 10V, V_O = 9.5V$ | -1.6 | | -1.3 | -2.2 | | -0.90 | | mA |
| | | $V_{DD} = 15V, V_O = 13.5V$ | -4.2 | | -3.4 | -8 | | -2.4 | | mA |
| I_{IN} | Input Current | $V_{DD} = 15V, V_{IN} = 0V$ | | -0.10 | | -10 ⁻⁵ | -0.10 | | -1.0 | μA |
| | | $V_{DD} = 15V, V_{IN} = 15V$ | | 0.10 | | 10 ⁻⁵ | 0.10 | | 1.0 | μA |

Schematic Diagram



TL/F/5956-3

DC Electrical Characteristics CD4023BC, CD4025BC (Note 2)

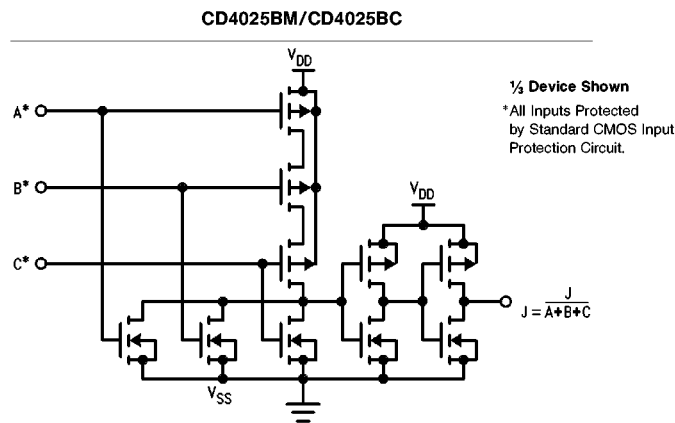
| Symbol | Parameter | Conditions | -40°C | | +25°C | | | +85°C | | Units |
|-----------------|---------------------------------------|---|---------------------------|------|-------|-------------------|------|-------|------|-------|
| | | | Min | Typ | Min | Typ | Max | Min | Max | |
| I _{DD} | Quiescent Device Current | V _{DD} = 5V | | 1.0 | | 0.004 | 1.0 | | 7.5 | μA |
| | | V _{DD} = 10V | | 2.0 | | 0.005 | 2.0 | | 15 | μA |
| | | V _{DD} = 15V | | 4.0 | | 0.006 | 4.0 | | 30 | μA |
| V _{OL} | Low Level Output Voltage | V _{DD} = 5V | | 0.05 | | 0 | 0.05 | | 0.05 | V |
| | | V _{DD} = 10V | | 0.05 | | 0 | 0.05 | | 0.05 | V |
| | | V _{DD} = 15V | | 0.05 | | 0 | 0.05 | | 0.05 | V |
| V _{OH} | High Level Output Voltage | V _{DD} = 5V | 4.95 | | 4.95 | 5 | | 4.95 | | V |
| | | V _{DD} = 10V | 9.95 | | 9.95 | 10 | | 9.95 | | V |
| | | V _{DD} = 15V | 14.95 | | 14.95 | 15 | | 14.95 | | V |
| V _{IL} | Low Level Input Voltage | V _{DD} = 5V, V _O = 4.5V | } I _O < 1μA | 1.5 | | 2 | 1.5 | | 1.5 | V |
| | | V _{DD} = 10V, V _O = 9.0V | | 3.0 | | 4 | 3.0 | | 3.0 | V |
| | | V _{DD} = 15V, V _O = 13.5V | | 4.0 | | 6 | 4.0 | | 4.0 | V |
| V _{IH} | High Level Input Voltage | V _{DD} = 5V, V _O = 0.5V | } I _O < 1μA | 3.5 | | 3.5 | 3 | | 3.5 | V |
| | | V _{DD} = 10V, V _O = 1.0V | | 7.0 | | 7.0 | 6 | | 7.0 | V |
| | | V _{DD} = 15V, V _O = 1.5V | | 11.0 | | 11.0 | 9 | | 11.0 | V |
| I _{OL} | Low Level Output Current (Note 3) | V _{DD} = 5V, V _O = 0.4V | 0.52 | | 0.44 | 0.88 | | 0.36 | | mA |
| | | V _{DD} = 10V, V _O = 0.5V | 1.3 | | 1.1 | 2.2 | | 0.90 | | mA |
| | | V _{DD} = 15V, V _O = 1.5V | 3.6 | | 3.0 | 8 | | 2.4 | | mA |
| I _{OH} | High Level Output Current (Note 3) | V _{DD} = 5V, V _O = 4.6V | -0.52 | | -0.44 | -0.88 | | -0.36 | | mA |
| | | V _{DD} = 10V, V _O = 9.5V | -1.3 | | -1.1 | -2.2 | | -0.90 | | mA |
| | | V _{DD} = 15V, V _O = 13.5V | -3.6 | | -3.0 | -8 | | -2.4 | | mA |
| I _{IN} | Input Current | V _{DD} = 15V, V _{IN} = 0V | | -0.3 | | -10 ⁻⁵ | -0.3 | | -1.0 | μA |
| | | V _{DD} = 15V, V _{IN} = 15V | | 0.3 | | 10 ⁻⁵ | 0.3 | | 1.0 | μA |

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

Note 2: V_{SS} = 0V unless otherwise specified.

Note 3: I_{OH} and I_{OL} are tested one output at a time.

Schematic Diagram



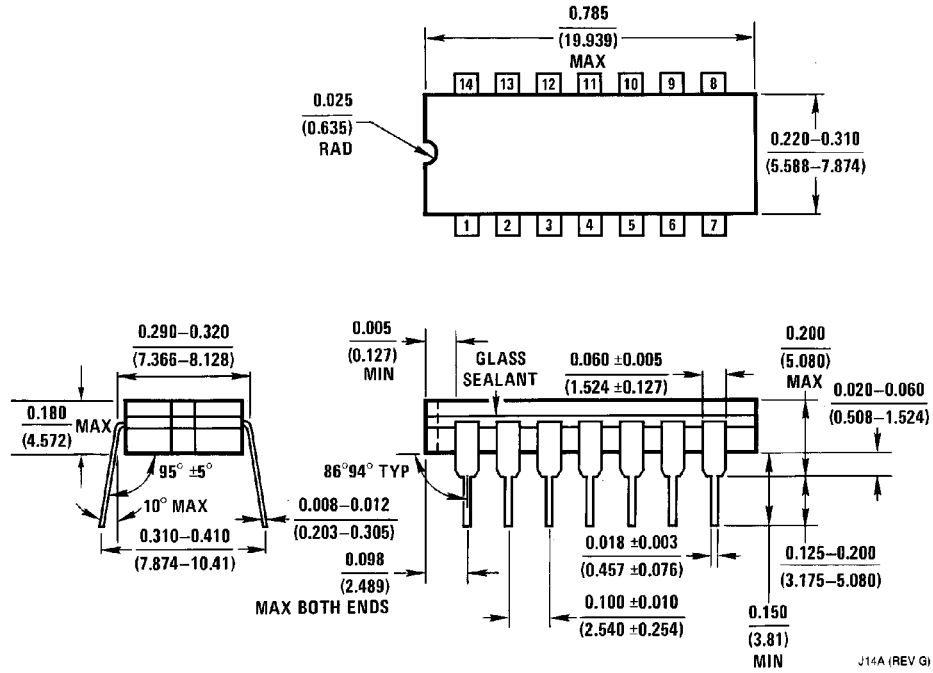
AC Electrical Characteristics* $T_A = 25^\circ\text{C}$, $C_L = 50\text{ pF}$, $R_L = 200\text{ k}$, unless otherwise specified

| Symbol | Parameter | Conditions | CD4023BC CD4023BM | | | CD4025BC CD4025BM | | | Units |
|------------------------|--------------------------------------|-----------------------|----------------------|-----|-----|----------------------|-----|-----|-------|
| | | | Min | Typ | Max | Min | Typ | Max | |
| t_{PHL} | Propagation Delay, High-to-Low Level | $V_{DD} = 5\text{V}$ | | 130 | 250 | | 130 | 250 | ns |
| | | $V_{DD} = 10\text{V}$ | | 60 | 100 | | 60 | 100 | ns |
| | | $V_{DD} = 15\text{V}$ | | 40 | 70 | | 40 | 70 | ns |
| t_{PLH} | Propagation Delay, Low-to-High Level | $V_{DD} = 5\text{V}$ | | 110 | 250 | | 120 | 250 | ns |
| | | $V_{DD} = 10\text{V}$ | | 50 | 100 | | 60 | 100 | ns |
| | | $V_{DD} = 15\text{V}$ | | 35 | 70 | | 40 | 70 | ns |
| t_{THL} t_{TLH} | Transition Time | $V_{DD} = 5\text{V}$ | | 90 | 200 | | 90 | 200 | ns |
| | | $V_{DD} = 10\text{V}$ | | 50 | 100 | | 50 | 100 | ns |
| | | $V_{DD} = 15\text{V}$ | | 40 | 80 | | 40 | 80 | ns |
| C_{IN} | Average Input Capacitance | Any Input | | 5 | 7.5 | | 5 | 7.5 | pF |
| C_{PD} | Power Dissipation Capacity (Note 4) | Any Gate | | 17 | | | 17 | | pF |

*AC Parameters are guaranteed by DC correlated testing.

Note 4: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics Application Note AN-90.

Physical Dimensions inches (millimeters)

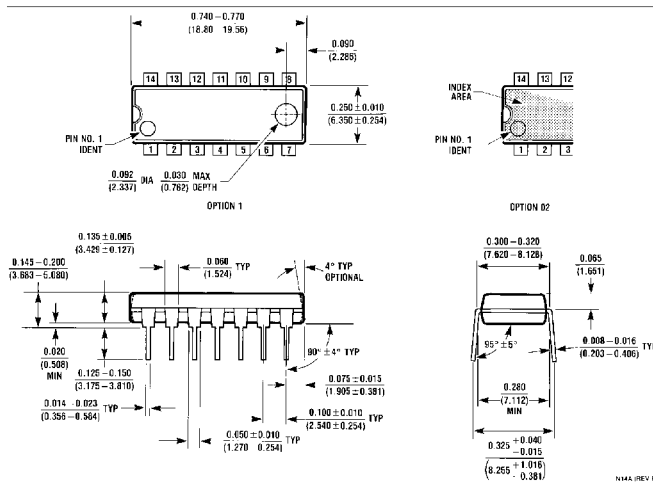


Ceramic Dual-In-Line Package (J)
Order Number CD4023BMJ, CD4023BCJ, CD4025BMJ or CD4025BCJ
NS Package Number J14A

J14A (REV G)

**CD4023BM/CD4023BC Buffered Triple 3-Input NAND Gate
 CD4025BM/CD4025BC Buffered Triple 3-Input NOR Gate**

Physical Dimensions inches (millimeters) (Continued)



Molded Dual-In-Line Package (N)
Order Number CD4023BMN, CD4023BCN, CD4025BMN or CD4025BCN
NS Package Number N14A

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



National Semiconductor Corporation
 1111 West Bardin Road
 Arlington, TX 76017
 Tel: 1(800) 272-9959
 Fax: 1(800) 737-7018

National Semiconductor Europe
 Fax: (+49) 0-180-530 85 86
 Email: cnjwge@tevm2.nsc.com
 Deutsch Tel: (+49) 0-180-530 85 85
 English Tel: (+49) 0-180-532 78 32
 Français Tel: (+49) 0-180-532 93 58
 Italiano Tel: (+49) 0-180-534 16 80

National Semiconductor Hong Kong Ltd.
 13th Floor, Straight Block,
 Ocean Centre, 5 Canton Rd.
 Tsimshatsui, Kowloon
 Hong Kong
 Tel: (852) 2737-1600
 Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
 Tel: 81-043-299-2309
 Fax: 81-043-299-2408

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